



PSMN071-100NSE

N-channel 100 V, 81 mOhm standard level 'ASFET with enhanced SOA' in DFN2020 package, designed specifically for Power-over-ethernet (PoE) applications

3 May 2022

Objective data sheet

1. General description

New standards and proprietary approaches are enabling Power-over-Ethernet (PoE) systems capable of delivering up to 90 W to each powered device (PD). Such solutions place increased demands on the power sourcing equipment (PSE) in terms of "soft-start", thermal management and power density requirements. PSMN071-100NSE is designed specifically for low power PoE applications.

2. Features and benefits

- Enhanced safe operating area (SOA) for superior linear mode operation
- Low R_{DSon} for low I^2R conduction losses
- 2 mm x 2 mm space-saving DFN2020 package, 60% smaller footprint than LFPAK33
- Very low I_{DSS} leakage

3. Applications

- PoE applications (<60 W)
- IEEE802.3at and proprietary PoE solutions
- Fault tolerant load switch - inrush management and eFuse applications
- Battery management applications

4. Quick reference data

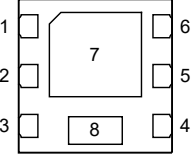
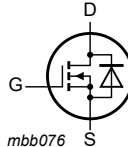
Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{DS}	drain-source voltage	$25\text{ }^{\circ}\text{C} \leq T_j \leq 175\text{ }^{\circ}\text{C}$	-	-	100	V
I_D	drain current	$V_{GS} = 10\text{ V}; T_{mb} = 25\text{ }^{\circ}\text{C}$	-	-	13	A
P_{tot}	total power dissipation	$T_{mb} = 25\text{ }^{\circ}\text{C}; \text{Fig. 1}$	-	-	28	W
Static characteristics						
R_{DSon}	drain-source on-state resistance	$V_{GS} = 10\text{ V}; I_D = 5\text{ A}; T_j = 25\text{ }^{\circ}\text{C}$	-	58	81	m Ω

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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	D	drain	 <p>Transparent top view DFN2020M-6 (SOT1220-2)</p>	 <p>mbb076</p>
2	D	drain		
3	G	gate		
4	S	source		
5	D	drain		
6	D	drain		
7	D	drain		
8	S	source		

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PSMN071-100NSE	DFN2020M-6	plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals; body 2 x 2 x 0.65 mm	SOT1220-2

7. Marking

Table 4. Marking codes

Type number	Marking code
PSMN071-100NSE	ZU

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage	$25\text{ °C} \leq T_j \leq 175\text{ °C}$	-	100	V
V_{DGR}	drain-gate voltage	$25\text{ °C} \leq T_j \leq 175\text{ °C}$; $R_{GS} = 20\text{ k}\Omega$	-	100	V
V_{GS}	gate-source voltage		-20	20	V
P_{tot}	total power dissipation	$T_{mb} = 25\text{ °C}$; Fig. 1	-	28	W
I_D	drain current	$V_{GS} = 10\text{ V}$; $T_{mb} = 25\text{ °C}$	-	13	A
		$V_{GS} = 10\text{ V}$; $T_{mb} = 100\text{ °C}$	-	9	A
I_{DM}	peak drain current	pulsed; $t_p \leq 10\text{ }\mu\text{s}$; $T_{mb} = 25\text{ °C}$; Fig. 2	-	51	A
T_{stg}	storage temperature		-55	175	°C
T_j	junction temperature		-55	175	°C
$T_{sld(M)}$	peak soldering temperature		-	260	°C
Source-drain diode					
I_S	source current	$T_{mb} = 25\text{ °C}$	-	13	A
I_{SM}	peak source current	pulsed; $t_p \leq 10\text{ }\mu\text{s}$; $T_{mb} = 25\text{ °C}$	-	51	A

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Symbol	Parameter	Conditions	Min	Max	Unit	
Avalanche ruggedness						
$E_{DS(AL)S}$	non-repetitive drain-source avalanche energy	$I_D = 6.6 \text{ A}$; $V_{sup} \leq 100 \text{ V}$; $R_{GS} = 50 \Omega$; $V_{GS} = 10 \text{ V}$; $T_{j(\text{init})} = 25 \text{ }^\circ\text{C}$; unclamped	[1]	-	10.8	mJ
I_{AS}	non-repetitive avalanche current	$V_{sup} = 100 \text{ V}$; $V_{GS} = 10 \text{ V}$; $T_{j(\text{init})} = 25 \text{ }^\circ\text{C}$; $R_{GS} = 50 \Omega$	[1]	-	6.6	A

[1] Protected by 100% test

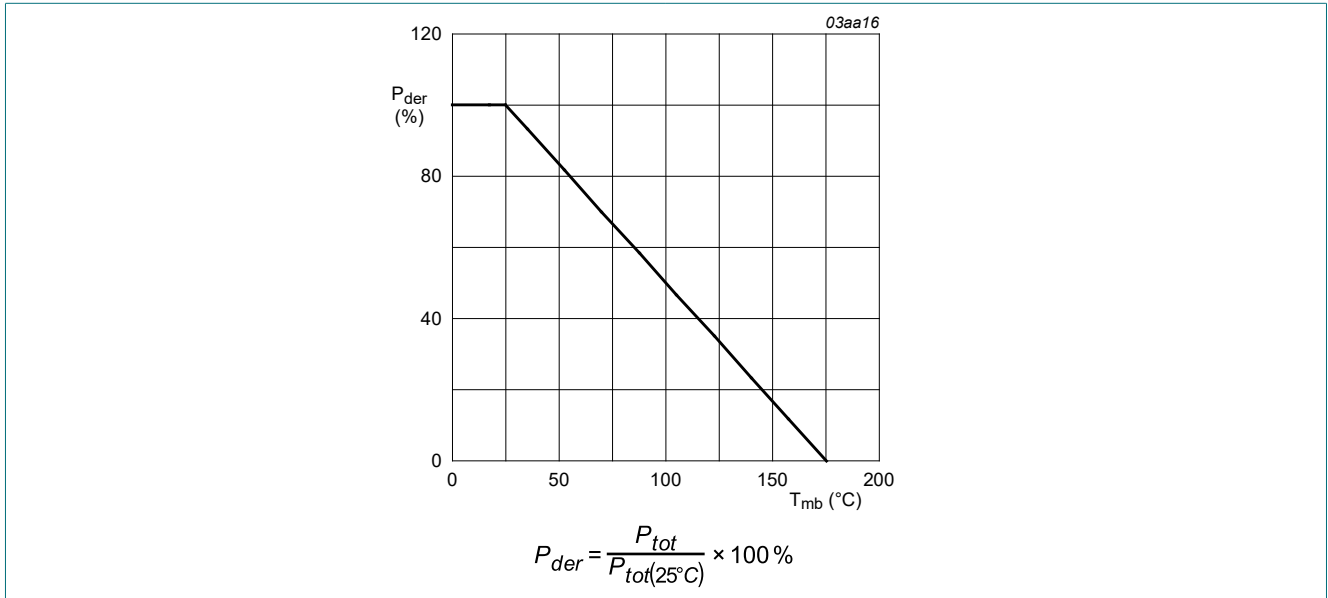


Fig. 1. Normalized total power dissipation as a function of mounting base temperature

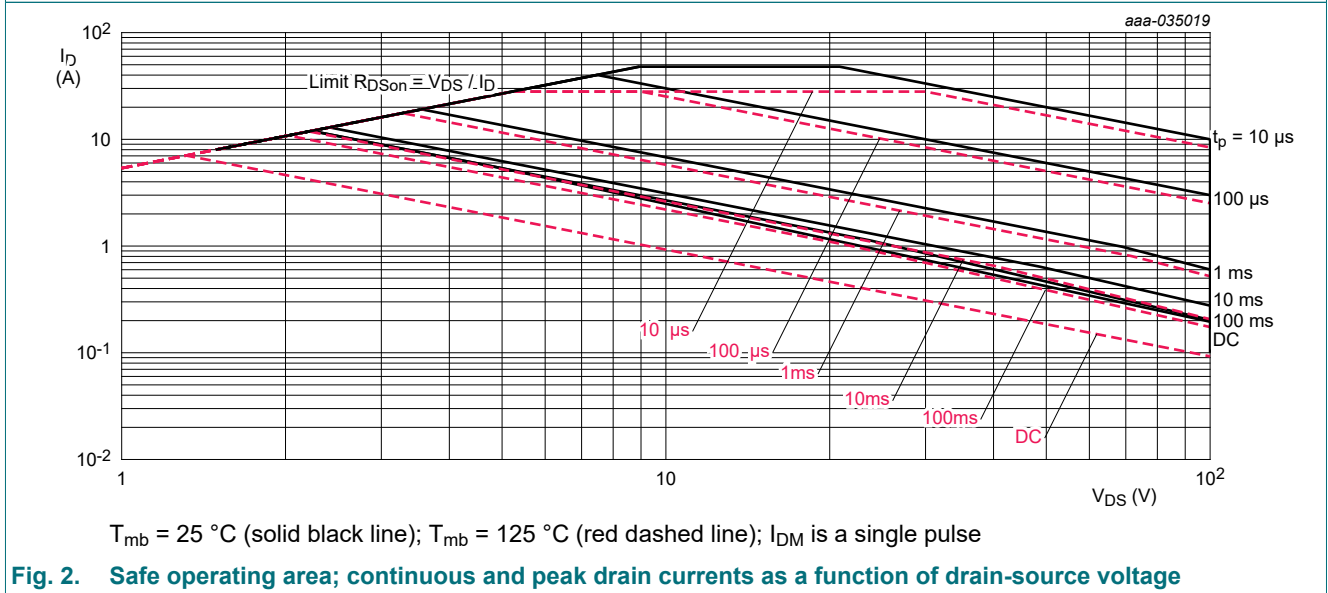


Fig. 2. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base		-	[tbd]	5.4	K/W

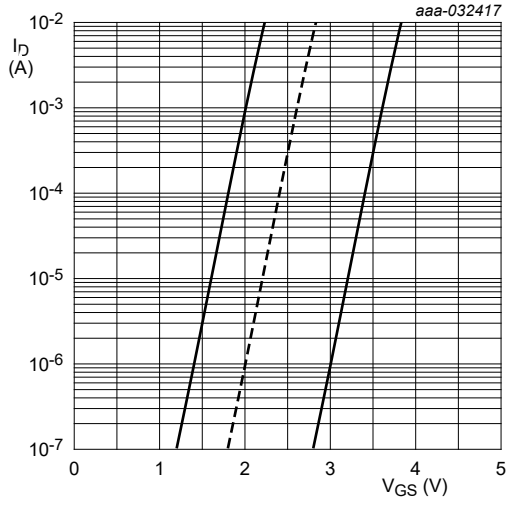
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10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 \text{ }^\circ C$	100	-	-	V
		$I_D = 250 \mu A; V_{GS} = 0 V; T_j = -55 \text{ }^\circ C$	90	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS}=V_{GS}; T_j = 25 \text{ }^\circ C; \text{ Fig. 3}$	2	2.6	3.6	V
		$I_D = 1 \text{ mA}; V_{DS}=V_{GS}; T_j = 175 \text{ }^\circ C$	-	[tbd]	-	V
		$I_D = 1 \text{ mA}; V_{DS}=V_{GS}; T_j = -55 \text{ }^\circ C$	-	[tbd]	-	V
$\Delta V_{GS(th)}/\Delta T$	gate-source threshold voltage variation with temperature	$25 \text{ }^\circ C \leq T_j \leq 150 \text{ }^\circ C$	-	[tbd]	-	mV/K
I_{DSS}	drain leakage current	$V_{DS} = 100 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ }^\circ C$	-	[tbd]	1	μA
		$V_{DS} = 100 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 125 \text{ }^\circ C$	-	-	100	μA
I_{GSS}	gate leakage current	$V_{DS} = 20 \text{ V}; T_j = 25 \text{ }^\circ C$	-	2	100	nA
		$V_{DS} = -20 \text{ V}; T_j = 25 \text{ }^\circ C$	-	2	100	nA
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = 10 \text{ V}; I_D = 5 \text{ A}; T_j = 25 \text{ }^\circ C$	-	58	81	m Ω
		$V_{GS} = 10 \text{ V}; I_D = 5 \text{ A}; T_j = 100 \text{ }^\circ C$	-	90	129	m Ω
		$V_{GS} = 10 \text{ V}; I_D = 5 \text{ A}; T_j = 175 \text{ }^\circ C$	-	128	184	m Ω
R_G	gate resistance	$f = 1 \text{ MHz}; T_j = 25 \text{ }^\circ C$	[tbd]	0.8	[tbd]	Ω
Dynamic characteristics						
$Q_{G(tot)}$	total gate charge	$I_D = 25 \text{ A}; V_{DS} = 50 \text{ V}; V_{GS} = 10 \text{ V}; T_j = 25 \text{ }^\circ C$	[tbd]	4.7	[tbd]	nC
		$I_D = 0 \text{ A}; V_{DS} = 0 \text{ V}; V_{GS} = 10 \text{ V}$	-	2.5	-	nC
Q_{GS}	gate-source charge	$I_D = 25 \text{ A}; V_{DS} = 50 \text{ V}; V_{GS} = 10 \text{ V}; T_j = 25 \text{ }^\circ C$	[tbd]	1.4	[tbd]	nC
$Q_{GS(th)}$	pre-threshold gate-source charge		-	0.9	-	nC
$Q_{GS(th-pl)}$	post-threshold gate-source charge		-	0.5	-	nC
Q_{GD}	gate-drain charge		[tbd]	0.9	[tbd]	nC
$V_{GS(pl)}$	gate-source plateau voltage	$I_D = 25 \text{ A}; V_{DS} = 50 \text{ V}; T_j = 25 \text{ }^\circ C$	-	4.5	-	V
C_{iss}	input capacitance	$V_{DS} = 50 \text{ V}; V_{GS} = 0 \text{ V}; f = 1 \text{ MHz}; T_j = 25 \text{ }^\circ C$	[tbd]	330	[tbd]	pF
C_{oss}	output capacitance		[tbd]	72	[tbd]	pF
C_{rss}	reverse transfer capacitance		[tbd]	2.3	[tbd]	pF
$t_{d(on)}$	turn-on delay time	$V_{DS} = 50 \text{ V}; R_L = 2 \text{ }^\circ \Omega; V_{GS} = 10 \text{ V}; R_{G(ext)} = 5 \text{ }^\circ \Omega; T_j = 25 \text{ }^\circ C$	-	1.2	-	ns
t_r	rise time		-	1	-	ns
$t_{d(off)}$	turn-off delay time		-	2.9	-	ns
t_f	fall time		-	1.4	-	ns
Source-drain diode						
V_{SD}	source-drain voltage	$I_S = 25 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ }^\circ C$	-	-	1.2	V
t_{rr}	reverse recovery time	$I_S = 25 \text{ A}; dI_S/dt = -100 \text{ A}/\mu s; V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}; \text{ Fig. 4}$	-	30	-	ns
Q_r	recovered charge	$I_S = 25 \text{ A}; dI_S/dt = -100 \text{ A}/\mu s; V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}; T_j = 25 \text{ }^\circ C; \text{ Fig. 4}$	-	21	-	nC

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$T_j = 25\text{ °C}; V_{DS} = 5\text{ V}$

Fig. 3. Sub-threshold drain current as a function of gate-source voltage

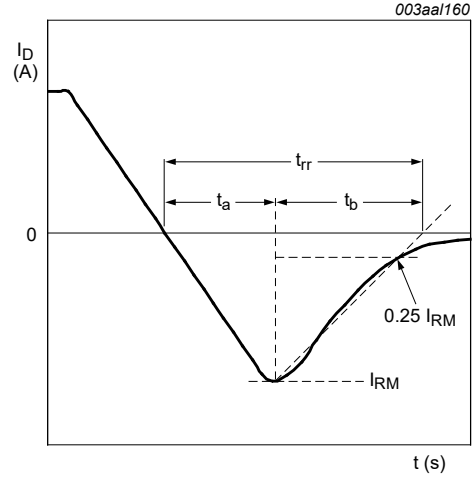


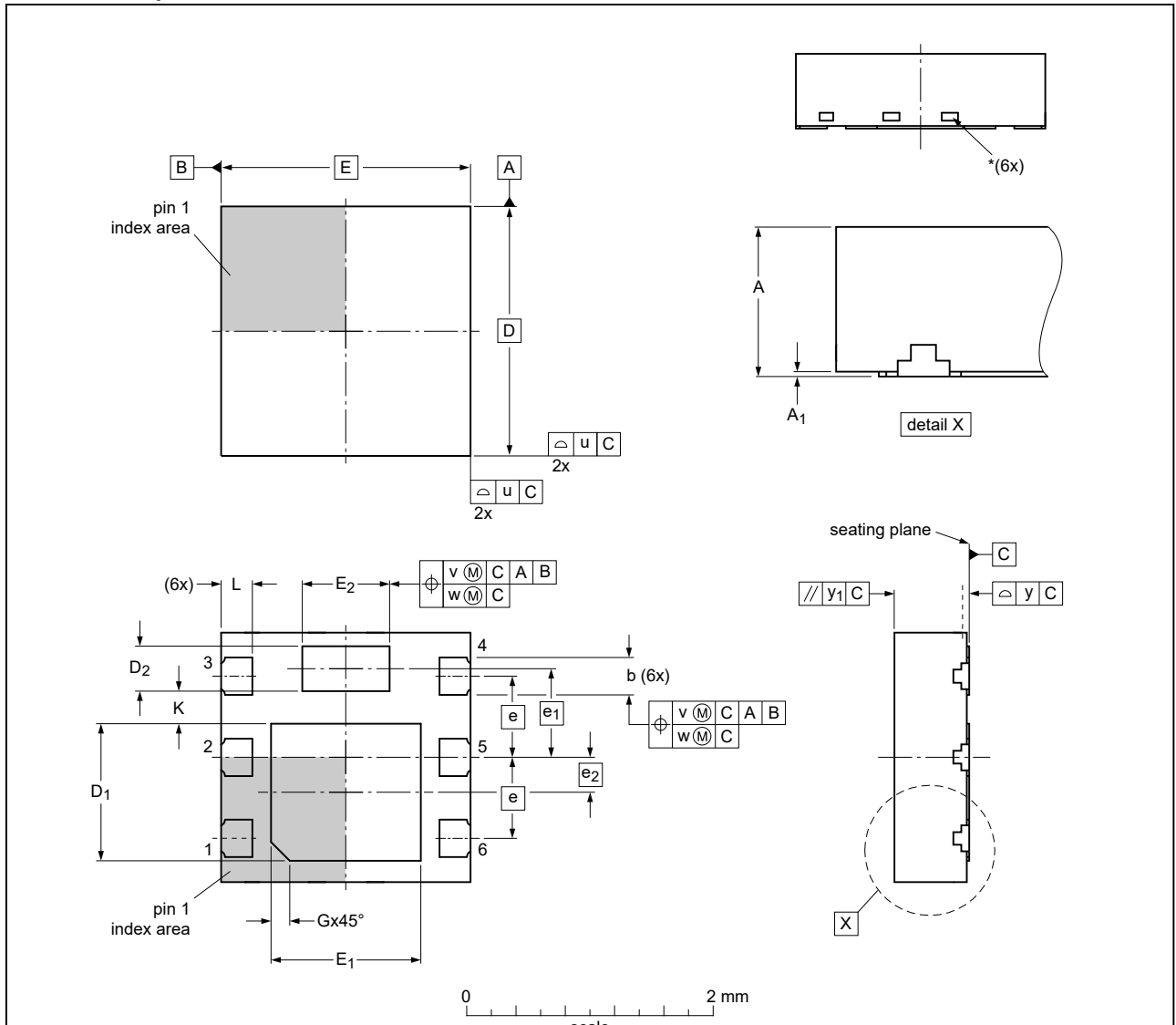
Fig. 4. Reverse recovery timing definition

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11. Package outline

DFN2020M-6: plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals; body 2 x 2 x 0.65 mm

SOT1220-2



Dimensions (mm are the original dimensions)

Unit	A	A ₁	b	D	D ₁	D ₂	E	E ₁	E ₂	e	e ₁	e ₂	G	K	L	u	v	w	y	y ₁
min	0.55	0	0.25	1.0	0.31	1.1	0.6													
mm nom	0.60	0.02	0.30	2	1.1	0.36	2	1.2	0.7	0.65	0.71	0.28	0.15 (ref)	0.2	0.20	0.25	0.05	0.1	0.05	0.05
max	0.65	0.04	0.35	1.2	0.41	1.3	0.8									0.30				

Note

1. Dimension A is including plating thickness.
2. * Visible depend upon used manufacturing technology.

sot1220-2_po

Outline version	References				European projection	Issue date
	IEC	JEDEC	JEITA			
SOT1220-2		---				-20-03-31- 20-04-01

Fig. 5. Package outline DFN2020M-6 (SOT1220-2)

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12. Soldering

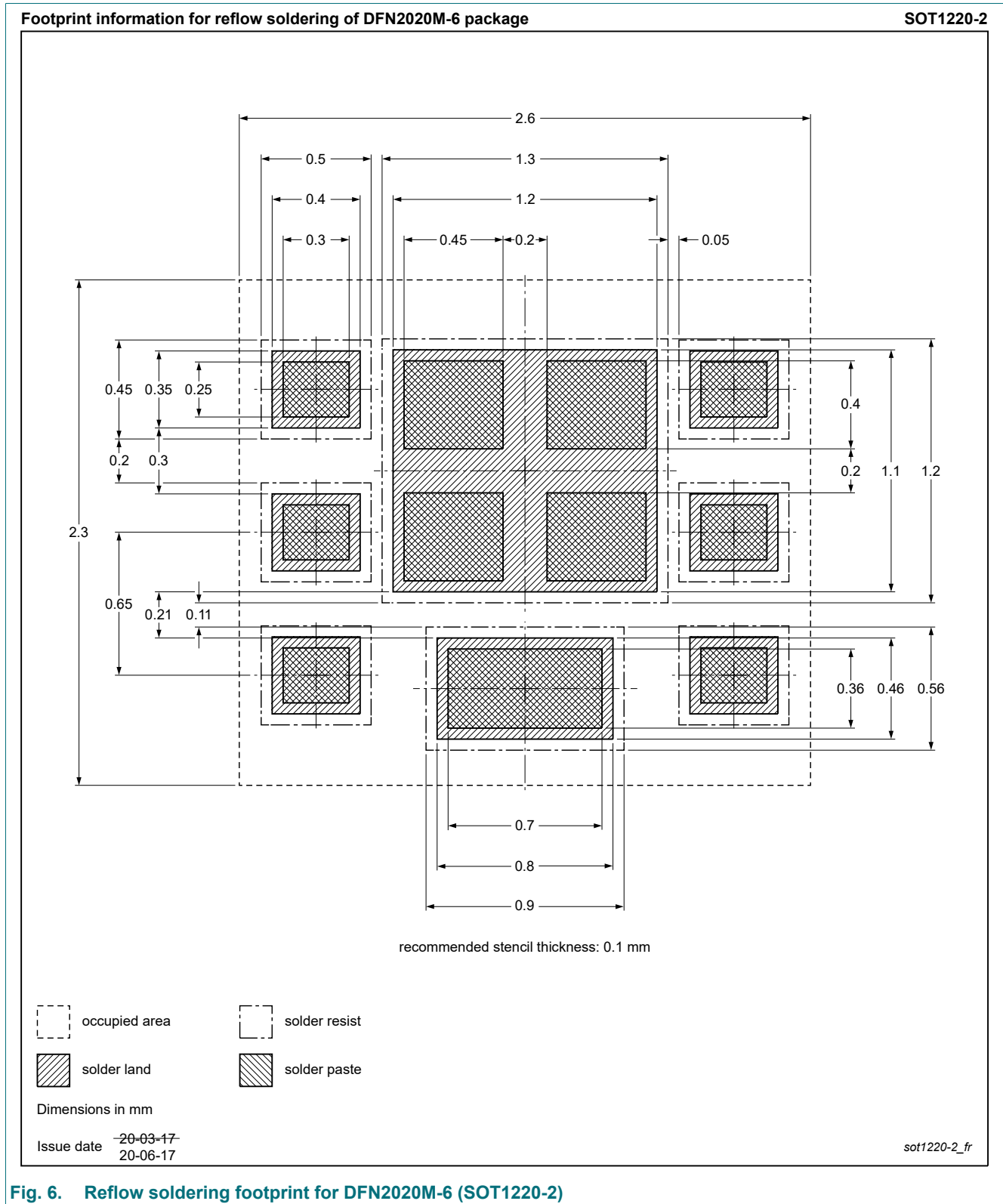


Fig. 6. Reflow soldering footprint for DFN2020M-6 (SOT1220-2)

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13. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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